

### ■ Features, Benefits and Applications

- 200 - 1000 kHz frequency range (contact SiTime for <200 kHz)
- Frequency stability as low as  $\pm 20$  PPM
- LVCMOS/LVTTL compatible output
- Typical current consumption of 5.7 mA in active mode
- Standby or output enable modes
- Four industry-standard packages: 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm
- All-silicon device with outstanding reliability of 2 FIT, 10x improvement over quartz-based devices, enhancing system MTBF
- Outstanding mechanical robustness for portable applications
- Ultra short lead time
- Ideal for consumer electronics, audio applications

### ■ Specifications

#### Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Output Frequency Range	f	200	—	1000	kHz	Contact SiTime for <200 kHz
Frequency Stability	F_stab	-20	—	+20	PPM	Inclusive of: Initial stability, operating temperature, rated power, supply voltage change, load change, shock and vibration.  <b><math>\pm 20</math> PPM available in extended commercial temperature only</b>
		-25	—	+25	PPM	
		-30	—	+30	PPM	
		-50	—	+50	PPM	
Aging	Ag	-1.0	—	1.0	PPM	1st year at 25°C
Operating Temperature Range	T_use	-20	—	+70	°C	Extended commercial
		-40	—	+85	°C	Industrial
Supply Voltage	Vdd	1.71	1.8	1.89	V	
		2.25	2.5	2.75	V	
		2.52	2.8	3.08	V	
		2.97	3.3	3.63	V	
Current Consumption	Idd	—	5.9	6.9	mA	No load condition, f = 400 KHz, Vdd = 2.5 V, 2.8 V or 3.3 V
		—	5.7	6.6	mA	No load condition, f = 400 KHz, Vdd = 1.8 V
Standby Current	I_std	—	2.4	4.3	μA	ST = GND, Vdd = 3.3 V, Output is weakly pulled down
		—	1.2	2.2	μA	ST = GND, Vdd = 2.5 or 2.8 V, Output is weakly pulled down
		—	0.4	0.8	μA	ST = GND, Vdd = 1.8 V, Output is weakly pulled down
Duty Cycle	DC	45	50	55	%	All Vdds
Rise/Fall Time	Tr, Tf	—	1.0	2.0	ns	20% - 80% Vdd=2.5V or 2.8V, 3.3V, 15pF load
		—	1.3	2.5	ns	20% - 80% Vdd=1.8V, 15pF load
Output Voltage High	VOH	90%	—	—	Vdd	IOH = -4 mA (Vdd = 3.3 V) IOH = -3 mA (Vdd = 2.8 V and Vdd = 2.5 V) IOH = -2 mA (Vdd = 1.8 V)
Output Voltage Low	VOL	—	—	10%	Vdd	IOL = 4 mA (Vdd = 3.3 V) IOL = 3 mA (Vdd = 2.8 V and Vdd = 2.5 V) IOL = 2 mA (Vdd = 1.8 V)
Output Load	Ld	—	—	15	pF	At maximum frequency and supply voltage. Contact SiTime for higher output load option
Input Voltage High	VIH	70%	—	—	Vdd	Pin 1, OE or ST
Input Voltage Low	VIL	—	—	30%	Vdd	Pin 1, OE or ST
Startup Time	T_osc	—	—	10	ms	Measured from the time Vdd reaches its rated minimum value
Resume Time	T_resume	—	3	4	ms	Measured from the time ST pin crosses 50% threshold
RMS Period Jitter	T_jitt	—	11	17	ps	f = 400 KHz, Vdd = 2.5 V, 2.8 V or 3.3 V
		—	12	17	ps	f = 400 KHz, Vdd = 1.8 V

## ■ Specifications (Cont.)

### Pin Description Tables

Pin #1 Functionality
<b>OE</b>
H or Open <sup>[1]</sup> : specified frequency output
L: output is high impedance
<b><math>\overline{\text{ST}}</math></b>
H or Open: specified frequency output
L: output is low level (weak pull down). Oscillation stops

Pin Map	
Pin	Connection
1	OE/ $\overline{\text{ST}}$
2	GND
3	CLK
4	VDD

### Absolute Maximum Table

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

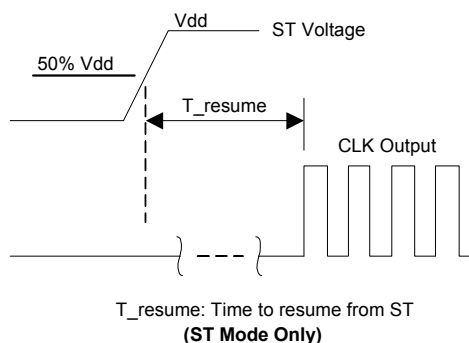
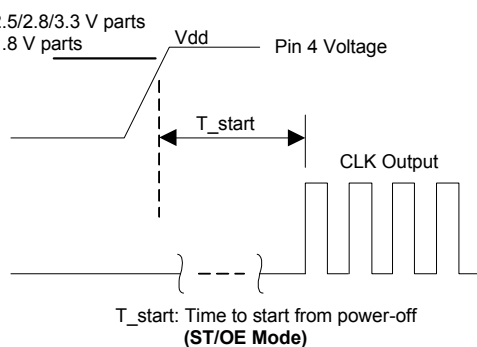
Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
Vdd	-0.5	4	V
Electrostatic Discharge	–	6000	V
Theta JA (with copper plane on Vdd and GND)	–	75	°C/W
Theta JC (with PCB traces of 0.010 inch to all pins)	–	24	°C/W
Soldering Temperature (follow standard Pb free soldering guidelines)	–	260	°C
Number of Program Writes	–	1	NA
Program Retention over -40 to 125°C, Process, Vdd (0 to 3.65 V)	1,000+	–	years

### Environmental Compliance

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL1 @ 260°C

### Startup and Resume Timing Diagram

90% Vdd: 2.5/2.8/3.3 V parts  
95% Vdd: 1.8 V parts



#### Note:

1. In 1.8 V mode, a resistor of <100 kΩ between OE pin and VDD is recommended.

### ■ Dimensions and Land Patterns

Package Size – Dimensions (Unit: mm) <sup>[2]</sup>	Recommended Land Pattern (Unit: mm) <sup>[3]</sup>
<p><b>2.5 x 2.0 x 0.75 mm</b></p> <p>Top view dimensions: 2.5 ± 0.10, 2.0 ± 0.10, 0.75 ± 0.05. Pin locations: #1, #2, #3, #4. Marking: YXXXX.</p> <p>Side view dimensions: 0.75 ± 0.05.</p> <p>Bottom view dimensions: 1.00, 0.75, 0.5, 1.1.</p>	<p>Land pattern dimensions: 1.9, 1.5, 1.1, 1.0.</p>
<p><b>3.2 x 2.5 x 0.75 mm</b></p> <p>Top view dimensions: 3.2 ± 0.15, 2.5 ± 0.15, 0.75 ± 0.05. Pin locations: #1, #2, #3, #4. Marking: YXXXX.</p> <p>Side view dimensions: 0.75 ± 0.05.</p> <p>Bottom view dimensions: 2.1, 0.9, 0.7, 0.9.</p>	<p>Land pattern dimensions: 2.2, 1.9, 1.4, 1.2.</p>
<p><b>5.0 x 3.2 x 0.75 mm</b></p> <p>Top view dimensions: 5.0 ± 0.15, 3.2 ± 0.15, 0.75 ± 0.05. Pin locations: #1, #2, #3, #4. Marking: YXXXX.</p> <p>Side view dimensions: 0.75 ± 0.05.</p> <p>Bottom view dimensions: 2.39, 1.1, 1.15, 0.8.</p>	<p>Land pattern dimensions: 2.54, 2.2, 1.6, 1.5.</p>
<p><b>7.0 x 5.0 x 0.90 mm</b></p> <p>Top view dimensions: 7.0 ± 0.15, 5.0 ± 0.15, 0.90 ± 0.10. Pin locations: #1, #2, #3, #4. Marking: YXXXX.</p> <p>Side view dimensions: 0.90 ± 0.10.</p> <p>Bottom view dimensions: 5.08, 1.4, 1.1, 2.6.</p>	<p>Land pattern dimensions: 5.08, 3.81, 2.0, 2.2.</p>

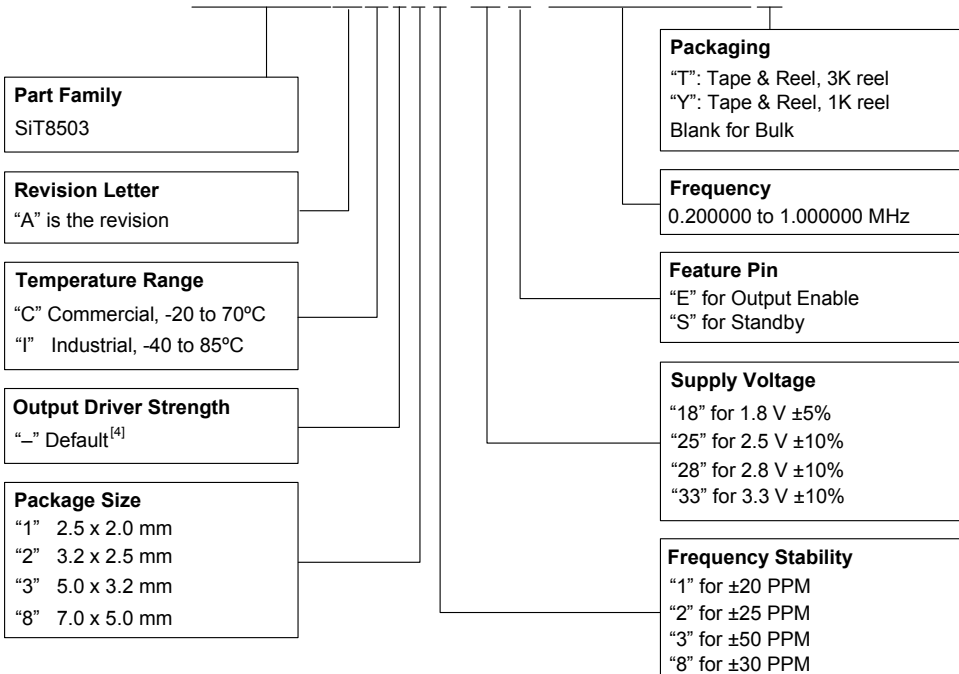
#### Notes:

- Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
- A capacitor of value 0.1  $\mu$ F between Vdd and GND is recommended.

## ■ Part No. Guide – How to Order

The Part No. Guide is for reference only. For real-time customization and exact part number, use the SiTime [Part Number Generator](#).

## SiT8503AC-23-33E-000.751234T

**Notes:**

4. Contact SiTime for different drive strength options for driving higher loads or reducing EMI.

**Frequency Stability vs. Temperature Range Options**

Frequency Stability (PPM)	Temperature Range	Supply Voltage			
		1.8 V	2.5 V	2.8 V	3.3 V
±20	C (-20 to +70°C)	✓	✓	✓	✓
	I (-40 to +85°C)	–	–	–	–
±25	C (-20 to +70°C)	✓	✓	✓	✓
	I (-40 to +85°C)	–	–	–	–
±30	C (-20 to +70°C)	✓	✓	✓	✓
	I (-40 to +85°C)	–	–	–	–
±50	C (-20 to +70°C)	✓	✓	✓	✓
	I (-40 to +85°C)	–	–	–	–

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